NSN 5961-01-563-8168

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-563-8168 **Inclosure Material:** Ceramic **Overall Length:** Between 15.8 millimeters and 16.8 millimeters **Overall Width:** Between 25.8 millimeters and 27.6 millimeters **Internal Configuration:** Junction contact **Internal Junction Configuration:** Npn **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 30.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage source current minor **Power Rating Per Characteristic:** 18.60 watts small-signal input power, common-collector preset Shelf Life: N/a **Unit Of Measure: Demilitarization:** No